Small Signal Switching Diode multicomp





Features:

- Silicon Epitaxial Diode
- High Speed Switching Diode
- 500mW Power Dissipation

Mechanical Data:

- Case:MINI-MELF glass case
- Polarity: Colour band denotes cathode
- Weight: Approx. 0.031g

Maximum Ratings and Electrical Characteristics:

Ratings at 25°C ambient temperature unless otherwise specified

| Characteristics | Symbol | LL4148-13 | Units |
|--|-----------------|------------|-------|
| Reverse voltage | VR | 75 | V |
| Peak reverse voltage | V _{RM} | 100 | V |
| Average forward rectified current Half wave rectification with resistive load at ta=25°C and f ≥50Hz | lo | 150 | mA |
| Forward surge current at t <1S and T _J =25°C (Note 1) | Iгsм | 500 | mA |
| Power dissipation at Ta=25°C | Ptot | 500 | mW |
| Junction temperature | Тл | 175 | °C |
| Storage temperature range | Тѕтс | -55 to+175 | °C |

Note:

(1) Valid provided that electrodes are kept at ambient temperature



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Electrical Characteristics:

| Characteristics | | Min. | Тур. | Max. | Units |
|--|------|------|------|---------------|----------------|
| Forward voltage at I _F =10mA | VF | - | - | 1 | V |
| Leakage current at V _R =20V at V _R =75V at V _R =20V T _J =150°C | lr | - | - | 25 5 50 | nΑ μΑ μΑ |
| Capacitance at V _F =V _R =0V | Ctot | - | - | 4 | pF |
| Voltage rise when switching on tested with 50mA pulses tp=0.1µS, rise time <30ns, fp=5 to 100kHz | Vfr | - | - | 2.5 | V |
| Reverse recovery time from I _F =10mA V _R =6V, R _L =100,at I _R =1mA | trr | - | - | 4 | ns |
| Thermal resistance junction to ambient (Note1) | Reja | | | 350 | K/W |
| Rectification efficiency at 100MHz, VRF=2V | ηV | 0.45 | - | - | - |

Note

(1) Valid provided that electrodes are kept at ambient temperature

Fig. 1- Admissible Power Dissipation Versus **Ambient Temperature**

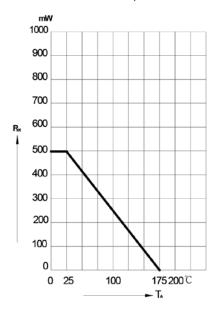
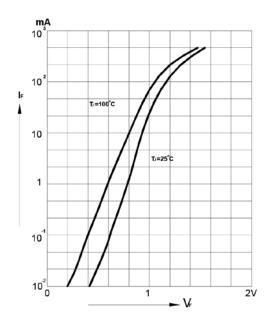


Fig. 2- Forward Characteristics



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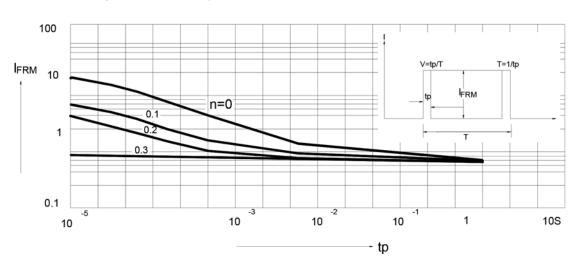
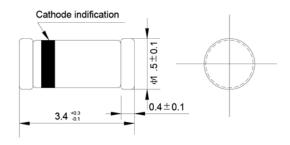


Fig. 3 -Admissible Repetitive Peak Forward Current Versus Pulse Duration

Dimensions:



Dimensions: Millimetres

Part Number Table

| Description | Part Number | | |
|------------------------------|-------------|--|--|
| Small Signal Switching Diode | LL4148-13 | | |

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